GND 8

SDLS003 D2632, JANUARY 1981 - REVISED MARCH 1988

- 8-Bit Counter with Register
- Parallel Register Outputs ٠
- Choice of 3-State ('LS590) or Open-Collector ('LS591) Register Outputs
- **Guaranteed Counter Frequency:** DC to 20 MHz
- description

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These devices each contain an 8-bit binary counter that feeds an 8-bit storage register. The storage register has parallel outputs. Separate clocks are provided for both the binary counter and storage register. The binary counter features a direct clear input CCLR and a count enable input CCKEN. For cascading, a ripple carry output RCO is provided. Expansion is easily accomplished for two stages by connecting RCO of the first stage to CCKEN of the second stage. Cascading for larger count chains can be accomplished by connecting RCO of each stage to CCK of the following stage.

Both the counter and register clocks are positive-edge triggered. If the user wishes to connect both clocks together, the counter state will always be one count ahead of the register. Internal circuitry prevents clocking from the clock enable.

SN54LS590, SN54LS591 . . . J OR W PACKAGE SN74LS590, SN74LS591 . . . N PACKAGE (TOP VIEW) QB []1 ОС Д2 15 🗌 ۵A 14 🗍 G 13 RCK QE ∐4 €F []5 12 CCKEN QC [[6 11] сск Ωн [] 7 10 CCLR

9 🗌

RCO

SN54LS590, SN54LS591 ... FK PACKAGE (TOP VIEW)



NC - No internal connection



schematics of inputs and outputs

PRODUCTION DATA documents contain information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



POST OFFICE BOX 655012 + DALLAS, TEXAS 15265



logic diagram (positive logic)

Pin numbers shown are for J, N and W packages.





[†]These symbols are in accordance with ANSI/IEEE Std. 91-1984 and IEC Publication 617-12. Pin numbers shown are for J, N, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, VCC (see Note 1)	7V
Input voltage	7V
Off-state output voltage	5.5 V
Operating free-air temperature range: SN54LS590, SN54LS591	- 55°C to 125°C
SN74LS590, SN74LS591	0°C to 70°C
Storage temperature range	-65°C to 150°C

NOTE 1: Voltage values are with respect to the network ground terminal.

recommended operating conditions

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			SN54LS'			SN74LS'			
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Vcc	Supply voltage		4.5	5	5.5	4.75	5	5.25	V
VIH	High-level input voltage		2			2			V
VIL	Low-level input voltage				0.7			0.8	V
Voн	High-level output voltage	Q, 'LS591 only			5.5			5.5	V
		RCO			1			- 1	
юн	High-level output current	Q, 'LS590 only			- 1	i		- 2.6	mA
1-	Low-level output current	RCÓ			8			16	mA
101		Q			12			24	
fock	Counter clock frequency		0		20	0		20	MHz
frck	Register clock frequency	0		25	0		25	MHz	
tw(CCK)	Duration of counter clock pulse					25			пѕ
Tw(CCLR)	Duration of counter clear pulse					20			ns
tw(RCK)	Duration of register clock pulse					20			ns
	Setup time	CCKEN low before CCK1	20			20			
t _{su}		CCLR inactive before CCK1	20			20			ns
		CCK before RCK1 (see Note 2)	40	•		40			
th	Hold time ČCKEN low after CCK f		0			0			ns
TA	Operating free-air temperatur	e	- 55		125	0		70	°C

NOTE 2: This setup time ensures the register will see stable data from the counter outputs. The clocks may be tied together in which case the register state will be one clock pulse behind the counter.



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					SN54LS'				LINHT			
	PARAMETE	. H	'	TEST CONDITIONSI		MIN	TYP‡	MAX	MIN	TYP‡	MAX	
Vik			V _{CC} = MIN,	I _I = - 18 mA				- 1.5			- 1.5	V
				<u> </u>	I _{OH} = - 1 mA	2.4	3.2				•	
VOH 1 LSS	L2220 C	LS590 Q		viH = 54'	1 _{OH} = - 2.6 mA				2,4	3.1		V
RCO			ľ	¹ OH = - 1 mA	2.4	3.2		2.4	3.2			
юн	'LS591 C	2	V _{CC} = MIN, VII = MAX	V _{IH} = 2 V,	V _{OH} = 5.5 V,			0.1		_	0.1	mA
					I _{O1} = 12 mA	ł	0.25	0.4		0.25	0.4	
	a		$V_{CC} = MIN,$	V _{IH} = 2 V,	IOL = 24 mA	+				0.35	0.5	
VOL			VIL = MAX		10L = 8 mA		0,25	0.4		0.25	0.4	Ý
	RCO				IOL = 16 mA					0.35	0.5	ĺ
Іогн	'LS590 C	5	V _{CC} = MAX, V _O = 2,7 V	VIH = 2 V,	VIL = MAX,			20			20	μА
loz∟	'LS590 C	ـــــــــــــــــــــــــــــــــــــ	V _{CC} = MAX, V _O = 0.4 V	V _{1H} = 2 V.	VIL = MAX,			- 20		_	- 20	μΑ
1	·		VCC = MAX,	V ₁ = 7 V		<u> </u>		0.1			0.1	mA
ЧΗ			V _{CC} = MAX,	VI = 2.7 V				20	1		20	μA
1	ССК		$\lambda = -MAX$	$V_{\rm c} = 0.4$ V				- 0,8			- 0.8	mA
'IL	All others		VCC - WAAA	V = 0.4 V				- 0.2			- 0.2	
1008	1LS590 C	2	$V_{OO} = MAX$	$V_{0} = 0 V$		- 30		- 130	- 30		- 130	mA
1058	RCO					- 20		- 100	- 20		- 100	
lcc		1CCH					33	55		33	55	
	'LS590 ICCL ICCZ 'LS591 ICCH	CCL	V _{CC} = MAX,				44	65		44	65	
		^I CCZ	All possible inp	uts grounded,		L	46	65		46	65	mА
		1ссн	All outputs ope	'n		L	35	55	<u> </u>	35	55	
		1CCL]	42	65		42	65	

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

↑ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions, ‡ All typical values are at V_{CC} = 5 V, T_A = 25°C § Not more than one output should be shorted at a time and the duration of the short-circuit should not exceed one second,

switching characteristics,	, V _{CC} = 5 V, T _A = 25°C (see note 3)
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PARAMETER	DADAMETER	FROM	то				'L\$590			'L8591																
	(INPUT)	(OUTPUT)	TEST CONDITIONS		MIN	TYP	MAX	MIN	TYP	MAX	UNIT															
fmax	RCK	a	$R_{L} = 667 \ \Omega,$	С _L ≕ 45 рF	20	35		20	35		MHz															
^t PLH	CCK1	RCO	D 1 kg	Q 20 - E		14	22	Γ	16	24	ns															
^t PHL	CCKt	RCO	$H = 1 K \Omega$	CL - 30 pF		20	30		25	38	ns															
tPLH	CCLRI	RCO				30	45		32	48	ns															
UPL H	RCKT	Q	R _L - 667 Ω,			12	18		25	38	ns															
TPHL	RCKt	Q		C - 45 - 5		22	33		28	42	ns															
^t PZH	Ğ↓	Q		ML - 967 32,	n [- 007 32,	HL - 007 32,	μΓ - 00/ 32,	μΓ - 007 32,	μΓ - 007 32,	HL - 007 32,	HL - 007 32,	HL - 007 32,	μΓ - 007 32,	μΓ - 907 32,	μΓ - 007 32,	μΓ - 00/ 32,	μΓ - 007 32,	μΓ - 007 32,	n[- 00/ 32,	n [- 007 32,	μΓ - 007 32,	μΓ - 907 32,	25 38			ns
tPZL	Ğı	Q					30	45				ns														
^t PHZ	1D	Q	R _L = 667 Ω,	Q	0 - 5 - 5		20	30				ns														
tPLZ	đt	Q		32, CL≖5pF		25	38				ns															
tplh	G↑	Q	 D 667 O						34	50	ns															
te Hi	G!	Q	HL=66732,	$H_{L} = 667.32$	CL = 45 pF			-		32	48	ns														

NOTE 3: Load circuits and voltage waveforms are shown in Section 1.



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